

STD12NF06L STD12NF06L-1

N-channel 60V - 0.08Ω - 12A - DPAK - IPAK STripFET™ II Power MOSFET

General features

Туре	V _{DSSS}	R _{DS(on)}	I _D
STD12NF06L	60V	<0.1Ω	12A
STD12NF06L-1	60V	<0.1Ω	12A

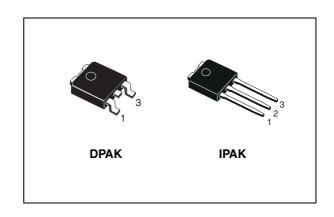
- Exceptional dv/dt capability
- Low gate charge

Description

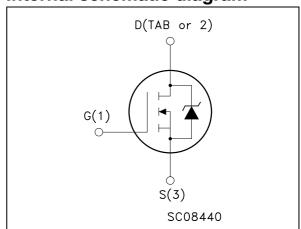
This Power MOSFET is the latest development of STMicroelectronics unique "Single Feature SizeTM" strip-based process. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and less critical alignment steps therefore a remarkable manufacturing reproducibility.

Applications

■ Switching application



Internal schematic diagram



Order codes

Part number	Marking	Package	Packaging
STD12NF06LT4	D12NF06L	DPAK	Tape & reel
STD12NF06L-1	F06L-1 D12NF06L IPAK		Tube

Contents STD12NF06L

Contents

1	Electrical ratings	3
2	Electrical characteristics	
3	2.1 Electrical characteristics (curves)	
4	Package mechanical data	
5	Packaging mechanical data1	
6	Revision history	13

STD12NF06L Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{DS}	Drain-source voltage (V _{GS} = 0)	60	٧
V _{DGR}	Drain-gate voltage ($R_{GS} = 20$ KΩ)	60	V
V_{GS}	Gate-source voltage	± 16	٧
I _D	Drain current (continuous) at T _C = 25°C	12	Α
I _D	Drain current (continuous) at T _C =100°C	8.5	Α
I _{DM} ⁽¹⁾	Drain current (pulsed)	48	Α
P _{TOT}	Total dissipation at T _C = 25°C	30	W
	Derating factor	0.2	W/°C
dv/dt (2)	Peak diode recovery voltage slope	15	V/ns
E _{AS} (3)	Single pulse avalanche energy	100	mJ
T _{stg}	Storage temperature	-55 to 175	°C
TJ	Max. operating junction temperature	-55 to 175	

^{1.} Pulse width limited by safe operating area

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case Max	5	°C/W
R _{thJA}	Thermal resistance junction-ambient Max	100	°C/W
T _I	Maximum lead temperature for soldering purpose	275	°C

577

 $^{2. \}quad I_{SD} \leq 12A, \; di/dt \leq 200A/\mu s, \; V_{DS} \leq 40V, \; T_J \leq T_{JMAX}$

^{3.} Starting $T_J = 25$ °C, $I_D = 6A$, $V_{DD} = 30V$

Electrical characteristics STD12NF06L

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Table 3. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D = 25 \text{mA}, V_{GS} = 0$	60			V
I _{DSS}	Zero gate voltage drain current (V _{GS} = 0)	V_{DS} = Max rating V_{DS} = Max rating, T_{C} = 125°C			1 10	μA μA
I _{GSS}	Gate body leakage current (V _{DS} = 0)	V _{GS} = ±20V			±100	nA
V _{GS(th)}	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1		2	V
R _{DS(on)}	Static drain-source on resistance	$V_{GS} = 10V, I_D = 6A$ $V_{GS} = 5V, I_D = 6A$		0.08 0.10	0.10 0.12	Ω Ω

Table 4. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
g _{fs} ⁽¹⁾	Forward transconductance	$V_{DS} = 25V_{,} I_{D} = 6A$		7		S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Reverse transfer capacitance	$V_{DS} = 25V, f = 1 \text{ MHz}, V_{GS} = 0$		350 75 30		pF pF pF
Q _g Q _{gs} Q _{gd}	Total gate charge Gate-source charge Gate-drain charge	$V_{DD} = 48V, I_{D} = 12A$ $V_{GS} = 5V$		7.5 2.5 3.0	10	nC nC nC

^{1.} Pulsed: pulse duration=300µs, duty cycle 1.5%

Table 5. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$t_{d(on)}$ t_{r} $t_{d(off)}$ t_{f}	Turn-on delay time Rise time Turn-off delay time Fall time	$V_{DD} = 30V$, $I_D = 6A$, $R_G = 4.7\Omega$, $V_{GS} = 4.5V$ Figure 12 on page 8		10 35 20 13		ns ns ns ns

Table 6. Source drain diode

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
I _{SD}	Source-drain current				12	Α
I _{SDM}	Source-drain current (pulsed)				48	Α
V _{SD} ⁽¹⁾	Forward on voltage	I _{SD} = 12A, V _{GS} = 0			1.5	V
t _{rr} Q _{rr} I _{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 12A, di/dt = 100A/ μ s, V_{DD} = 16V, T_{J} = 150°C Figure 14 on page 8		50 65 2.5		ns μC A

^{1.} Pulsed: pulse duration=300µs, duty cycle 1.5%

Electrical characteristics STD12NF06L

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

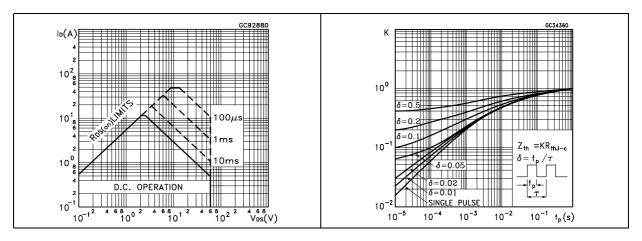


Figure 3. Output characteristics

Figure 4. Transfer characteristics

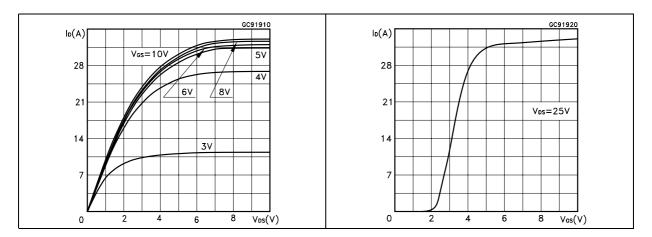
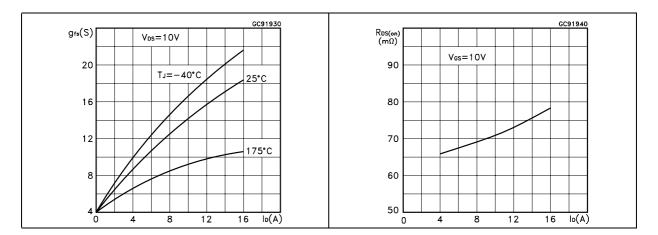


Figure 5. Transconductance

Figure 6. Static drain-source on resistance



6/14

Figure 7. Gate charge vs. gate-source voltage Figure 8. Capacitance variations

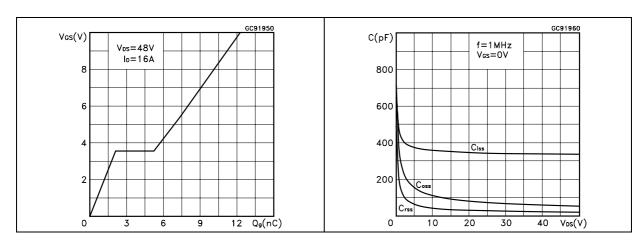


Figure 9. Normalized gate threshold voltage Figure 10. Normalized on resistance vs. vs. temperature temperature

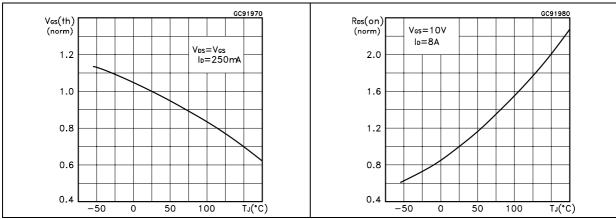
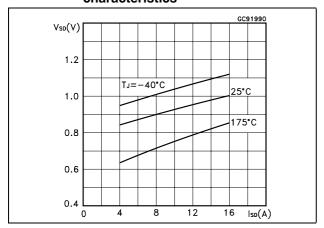


Figure 11. Source-drain diode forward characteristics



Test circuit STD12NF06L

3 Test circuit

Figure 12. Switching times test circuit for resistive load

Figure 13. Gate charge test circuit

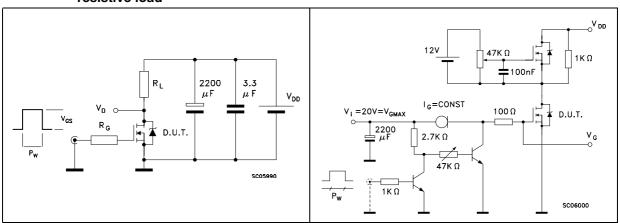


Figure 14. Test circuit for inductive load switching and diode recovery times

Figure 15. Unclamped Inductive load test circuit

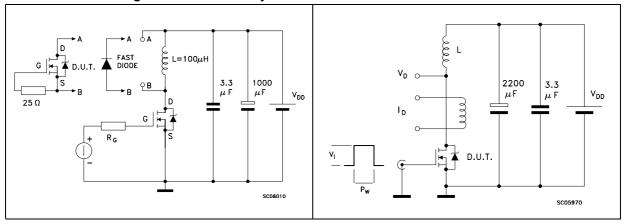
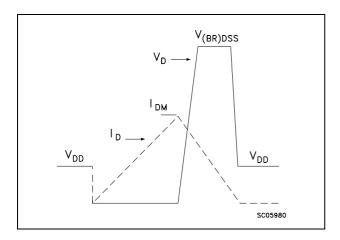


Figure 16. Unclamped inductive waveform



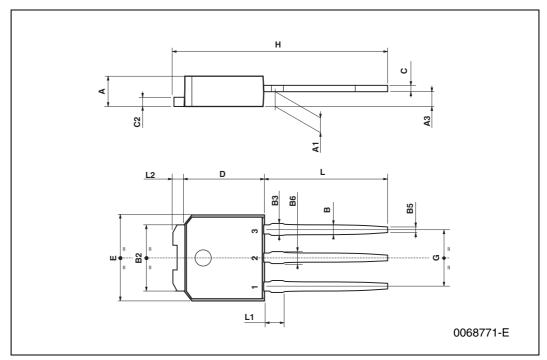
577

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

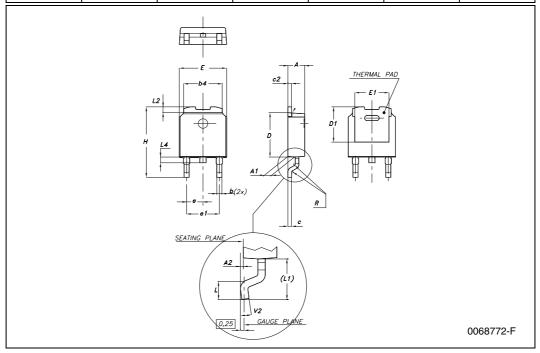
TO-251 (IPAK) MECHANICAL DATA

DIM.		mm			inch	
DIW.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
В	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
В3			0.85			0.033
B5		0.3			0.012	
B6			0.95			0.037
С	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
Н	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039



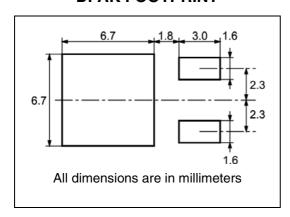
DPAK MECHANICAL DATA

DIM		mm.			inch		
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.	
Α	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
A2	0.03		0.23	0.001		0.009	
В	0.64		0.9	0.025		0.035	
b4	5.2		5.4	0.204		0.212	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
D1		5.1			0.200		
Е	6.4		6.6	0.252		0.260	
E1		4.7			0.185		
е		2.28			0.090		
e1	4.4		4.6	0.173		0.181	
Н	9.35		10.1	0.368		0.397	
L	1			0.039			
(L1)		2.8			0.110		
L2		0.8			0.031		
L4	0.6		1	0.023		0.039	
R		0.2			0.008		
V2	0°		8°	0°		8°	

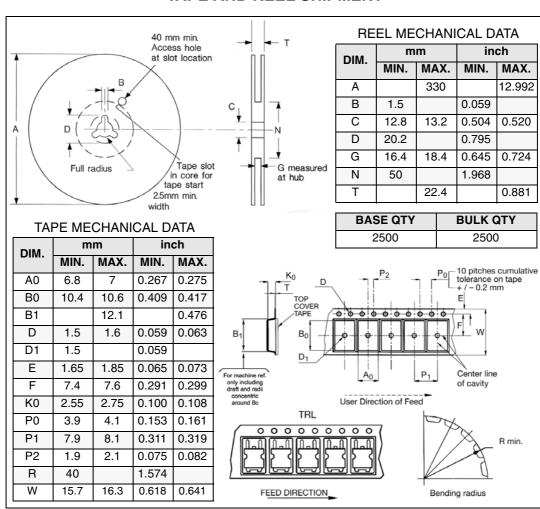


47/

5 Packaging mechanical data DPAK FOOTPRINT



TAPE AND REEL SHIPMENT



STD12NF06L Revision history

6 Revision history

Table 7. Revision history

Date	Revision	Changes
09-Sep-2004	4	Complete document
08-Aug-2006	5	New template, no content change
19-Feb-2007	6	Typo mistake on page 1

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

577

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for stmicroelectronics manufacturer:

Other Similar products are found below:

LD29300D2T25R M24M02-DWMN3TP/K AI-JTAGOPTO-1 BUV48A BZW04-15B LDK320AM33R SPC564A80CAL176

SPC56XVTOP-M STEVAL-ILL076V2 STEVAL-ISA175V1 STEVAL-VNH5050A STM32F207IGT7 STR91X-SK/RAI STTH12003TV1

STVNIM-EVAL M24C02-FDW6TP 417989F SG3525A ST7FLITE25F2M6 STEVAL-ILL079V1 STEVAL-ISF003V1 STL140N4F7AG

STM32F031F4P7 STM32F071CBU6 STM32F303VBT6 STM32F765ZIT6 STM32PRIM-LABUPG STM8A128-EVAL STW56N65DM2

LD29150DT18R LF50ABV P-NUCLEO-IHM002 VIPER38HDTR VIPER27LD VIPER16HN PD57070-E PD55003-E EVAL6226QR

EVAL6227PD EVAL6228QR EVALSP1340HDM EVLVIP16L-4WFL EV-VN7050AJ EV-VND5E025AK EV-VND7030AJ ANT2
M24LR16E T1610T-8T STY60NM50 STW23N85K5 STR736FV2T6